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| APPLICATION NO.           | FILING DATE              | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. |
|---------------------------|--------------------------|----------------------|---------------------|------------------|
| 10/813,528                | 03/30/2004               | Toshimasa Kobayashi  | 09794353-0033       | 5835             |
| 26263                     | 7590 07/28/2006          |                      | EXAM                | INER             |
|                           | HEIN NATH & ROS          | MULPURI,             | MULPURI, SAVITRI    |                  |
| P.O. BOX 061<br>WACKER DR | 080<br>IVE STATION, SEAR | S TOWER              | ART UNIT            | PAPER NUMBER     |
| CHICAGO, II               | L 60606-1080             |                      | 2812                |                  |

DATE MAILED: 07/28/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

|   |   | Application No.  | Applicant(s)   | 7          |  |  |
|---|---|--|--|------------|--|--|
| Office Action Summary                                 |   | 10/813,528   | KOBAYASHI ET AL.   |            |  |  |
|   |   | Examiner   | Art Unit   |            |  |  |
|   |   | Savitri Mulpuri  | 2812   |            |  |  |
| Period fo   | The MAILING DATE of this communication app<br>or Reply  | pears on the cover sheet with the o  | correspondence address   |            |  |  |
| WHIC<br>- Exter<br>after<br>- If NO<br>- Failu<br>Any | ORTENED STATUTORY PERIOD FOR REPLY CHEVER IS LONGER, FROM THE MAILING D. SIX (6) MONTHS from the mailing date of this communication. It is specified above, the maximum statutory period for reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing and patent term adjustment. See 37 CFR 1.704(b). | ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tircuit apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE   | N. mely filed  the mailing date of this communication. ED (35 U.S.C. § 133). |            |  |  |
| Status  |   |  |  |            |  |  |
| 1)⊠   | Responsive to communication(s) filed on 25 A  | pril 2006.   |  |            |  |  |
| 2a)⊠  | This action is <b>FINAL</b> . 2b) This action is non-final.   |  |  |            |  |  |
| 3)  | Since this application is in condition for allowance except for formal matters, prosecution as to the merits is   |  |  |            |  |  |
|   | closed in accordance with the practice under E  | Ex parte Quayle, 1935 C.D. 11, 4   | 53 O.G. 213.   |            |  |  |
| Dispositi   | on of Claims  |  |  |            |  |  |
| 5)□<br>6)⊠<br>7)□                                     | Claim(s) <u>1-8,12-21,27-39,42,44,46,48,50,52,5</u> 4a) Of the above claim(s) <u>40,41,47,49,51,53,55</u> Claim(s) is/are allowed. Claim(s) <u>1-8, 12-21, ,27-39,42,44,48,50,52,54</u> Claim(s) is/are objected to. Claim(s) are subject to restriction and/or   | 5,57 and 4345 is/are withdrawn fi<br>and 56 is/are rejected.   |  |            |  |  |
| Applicati   | ion Papers  |  |  |            |  |  |
| •   | The specification is objected to by the Examine The drawing(s) filed on is/are: a) acc Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct   | epted or b) objected to by the drawing(s) be held in abeyance. Se  | ee 37 CFR 1.85(a).   | <b>)</b> . |  |  |
| 11)   | The oath or declaration is objected to by the Ex  | kaminer. Note the attached Office  | Action or form PTO-152.  |            |  |  |
| Priority (  | ınder 35 U.S.C. § 119   |  |  |            |  |  |
| 12) [<br>a)   | Acknowledgment is made of a claim for foreign All b) Some * c) None of:  1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Burea See the attached detailed Office action for a list  | ts have been received. Is have been received in Applicative of the second in the secon | tion No<br>red in this National Stage  |            |  |  |
|   | ce of References Cited (PTO-892)  | 4) Interview Summar  |  |            |  |  |
| 3) Infor  | ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) er No(s)/Mail Date  | Paper No(s)/Mail D  5) Notice of Informal  6) Other:   | Date Patent Application (PTO-152)  |            |  |  |

Application/Control Number: 10/813,528

Art Unit: 2812

## **DETAILED ACTION**

This action is in response to the applicant's communication filed on 4/25/2006.

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-4, 7-8, 12-21, 42, 44, 46, 48,50,52,54,46 are rejected under 35 U.S.C. 102(a) as being anticipated by Motoki et al (US 6,667,184).

Motoki et al teaches laterally growing GaN layer on the GaN substrate(see abstract detailed description). Motoki particularly teaches striped shaped second regions and at least on of the second regions having a c-axis inverted relative to the first regions (see col. 24, lines 8-24).

Claims 5-6, 12-17, 27-39 are rejected under 35 U.S.C. 103(a) as being unpatentable over Motoki et al.

The formulae claimed in claim 5 and claim 6 is obvious in the invention of Motoki et al because similar materials are similar as claimed invention because GaN is grown on a patterned GaN substrate. Claimed shapes of second regions (claims 10,11, 19) and the claimed distance between two adjacent second regions (claims 12-17 and the

claimed diameter of the second regions and relative diameters of second and third regions (claims 22-26) are obvious because the dislocation density of second region higher than the dislocation density of the first region. Claimed defect densities in claim 29-30 in first and second and third regions are obvious in the invention of Motoki et al. It would have been obvious to one of ordinary skill in the art to chose different shapes of second region, different distance between he second regions and different diameter of second and third regions through routine optimization to obtain reduced dislocation densities in the active region, where the device is fabricated.

## Double Patenting

Claims 1, 42, 44,46,50,52,54,56 are provisionally rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims of copending Application No. 1-79,80.

This is a <u>provisional</u> obviousness-type double patenting rejection.

Claims 1,42,44,46,50,52,54,56 are provisionally rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims 1,79,80 of copending Application No. 11/148,771. Although the conflicting claims are not identical, they are not patentably distinct from each other because the scope of instant claims are encompassed by the scope of the application claims, wherein specifically "growing layers nitride III-V semiconductor layer for forming light emitting device" is recited".

This is a <u>provisional</u> obviousness-type double patenting rejection because the conflicting claims have not in fact been patented.

Applicant's arguments with respect to claims have been considered but are moot in view of the new ground(s) of rejection.

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Ito et al teaches GaN lateral growth on GaN substrate with growth preventing structure "804".

Application/Control Number: 10/813,528 Page 5

Art Unit: 2812

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Savitri Mulpuri whose telephone number is 57-72-1677. The examiner can normally be reached on Mon-Fri from 8 a.m. to 4.30 p.m.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Michael Lebentritt, can be reached on 571-272-1873. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Savitri Mulpuri Primary Examiner Art Unit 2812